



LOW INPUT VOLTAGE STEP-UP CONVERTER IN THIN SOT-23 PACKAGE

Check for Samples: TLV61220

FEATURES

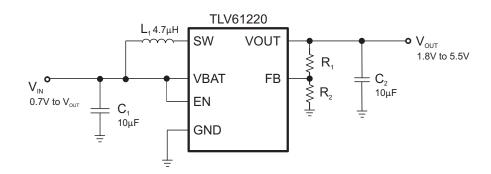
- Up to 95% Efficiency at Typical Operating Conditions
- 5.5 μA Quiescent Current
- Startup Into Load at 0.7 V Input Voltage
- Operating Input Voltage from 0.7 V to 5.5 V
- Pass-Through Function during Shutdown
- Minimum Switching Current 200 mA
- · Protections:
 - Output Overvoltage
 - Overtemperature
 - Input Undervoltage Lockout
- Adjustable Output Voltage from 1.8 V to 5.5 V
- · Small 6-pin Thin SOT-23 Package

APPLICATIONS

- Battery Powered Applications
 - 1 to 3 Cell Alkaline, NiCd or NiMH
 - 1 Cell Li-lon or Li-Primary
- Solar or Fuel Cell Powered Applications
- Consumer and Portable Medical Products
- Personal Care Products
- White or Status LEDs
- Smartphones

DESCRIPTION

The TLV61220 provides a power-supply solution for products powered by either a single-cell, two-cell, or three-cell alkaline, NiCd or NiMH, or one-cell Li-lon or Li-polymer battery. Possible output currents depend on the input-to-output voltage ratio. The boost converter is based on a hysteretic controller topology using synchronous rectification to obtain maximum efficiency at minimal quiescent currents. The output voltage of the adjustable version can be programmed by an external resistor divider, or is set internally to a fixed output voltage. The converter can be switched off by a featured enable pin. While being switched off, battery drain is minimized. The device is packaged in a 6-pin thin SOT-23 package (DBV).







These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

AVAILABLE DEVICE OPTIONS

T _A	OUTPUT VOLTAGE DC/DC Adjustable	PACKAGE	PART NUMBER
–40°C to 85°C	Adjustable	6-Pin SOT-23	TLV61220DBV

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_{IN}	Input voltage range on VBAT, SW, VOUT, EN, FB	- 0.3 to	7.5	٧
TJ	Operating junction temperature range	-40	150	°C
T _{stg}	Storage temperature range	-65	150	°C
FOD	Human Body Model (HBM) (2)		2	kV
ESD	Charged Device Model (CDM) ⁽²⁾		1.5	kV

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS TABLE

PACKAGE	THERMAL RESISTANCE Θ_{JA} ⁽¹⁾	THERMAL RESISTANCE Θ _{JB}	THERMAL RESISTANCE Θ _{JC}	POWER RATING T _A ≤ 25°C	DERATING FACTOR ABOVE T _A = 25°C
DBV	130 °C/W	27 °C/W	41 °C/W	769 mW	7.7 mW/°C

⁽¹⁾ Thermal ratings are determined assuming a high K PCB design according to JEDEC standard JESD51-7.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM MA	X	UNIT
V _{IN}	Supply voltage at VIN	0.7	;	5.5	V
T _A	Operating free air temperature range	-40		85	°C
TJ	Operating virtual junction temperature range	-40	1	25	°C

Product Folder Link(s): TLV61220

⁽²⁾ ESD testing is performed according to the respective JESD22 JEDEC standard.



ELECTRICAL CHARACTERISTICS

over recommended free-air temperature range and over recommended input voltage range (typical at an ambient temperature range of 25°C) (unless otherwise noted)

DC/DC ST	AGE						
	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IN}	Input voltage range			0.7		5.5	V
V _{IN}	Minimum input voltag	ge at startup	$R_{Load} \ge 150 \Omega$			0.7	V
V _{OUT}	TLV61220 output vol	Itage range	V _{IN} < V _{OUT}	1.8		5.5	V
V_{FB}	TLV61220 feedback	voltage		483	500	513	mV
I _{LH}	Inductor current rippl	le			200		mA
			$V_{OUT} = 3.3 \text{ V}, V_{IN} = 1.2 \text{ V}, T_A = 25 \text{ °C}$	220	400		mA
I_{SW}	switch current limit		$V_{OUT} = 3.3 \text{ V}, T_A = -40^{\circ}\text{C to } 85 ^{\circ}\text{C}$	180	400	5.5 0.7 5.5 500 513 200 400 400 400 600 550 5 % 0.5 0.5 0.2 0.5 1 0.01 0.01	mA
			$V_{OUT} = 3.3 \text{ V}, T_A = 0^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C}$	200	400		mA
	Rectifying switch on	resistance,	V _{OUT} = 3.3 V	1000 700		$m\Omega$	
R _{DS(on)}	HSD		V _{OUT} = 5 V		700		mΩ
	Main switch on resistance, LSD		V _{OUT} = 3.3 V		600		mΩ
	Main Switch on resis	tance, LSD	V _{OUT} = 5 V		550		mΩ
	Line regulation		V _{IN} < V _{OUT}		0.5 %		
	Load regulation		V _{IN} < V _{OUT}		0.5 %	0.7 5.5 0 513 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	
	Quiescent V _{II}	N	$I_{O} = 0 \text{ mA}, V_{EN} = V_{IN} = 1.2 \text{ V}, V_{OUT} = 3.3 \text{ V}$		0.5	0.9	μΑ
IQ	current V _C	DUT	10 = 0 111A, V _{EN} = V _{IN} = 1.2 V, V _{OUT} = 3.3 V		5	7.5	μΑ
I_{SD}	Shutdown current V _{II}	N	$V_{EN} = 0 \text{ V}, V_{IN} = 1.2 \text{ V}, V_{OUT} \ge V_{IN}$		0.2	0.5	μΑ
	Leakage current into	VOUT	V _{EN} = 0 V, V _{IN} = 1.2 V, V _{OUT} = 3.3 V		1		μΑ
I _{LKG}	Leakage current into	SW	V _{EN} = 0 V, V _{IN} = 1.2 V, V _{SW} = 1.2 V, V _{OUT} ≥ V _{IN}		0.01	0.2	μΑ
I _{FB}	TLV61220 Feedback current	c input	V _{FB} = 0.5 V		0.01		μΑ
I _{EN}	EN input current		Clamped on GND or V _{IN} (V _{IN} < 1.5 V)		0.005	0.1	μΑ

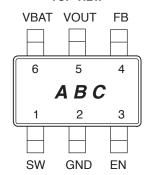
CONTRO	L STAGE					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IL}	EN input low voltage	V _{IN} ≤ 1.5 V			$0.2 \times V_{IN}$	V
V_{IH}	EN input high voltage	V _{IN} ≤ 1.5 V	$0.8 \times V_{IN}$			V
V_{IL}	EN input low voltage	5 V > V _{IN} > 1.5 V			0.4	V
V_{IH}	EN input high voltage	5 V > V _{IN} > 1.5 V	1.2			V
V_{UVLO}	Undervoltage lockout threshold for turn off	V _{IN} decreasing		0.5	0.7	V
	Overvoltage protection threshold		5.5		7.5	V
	Overtemperature protection			140		°C
	Overtemperature hysteresis			20		°C

Product Folder Link(s): TLV61220



PIN ASSIGNMENTS

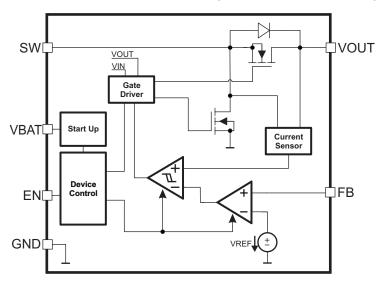
DBV PACKAGE TOP VIEW



Terminal Functions

TERM	INAL	I/O	DESCRIPTION					
NAME	NO.	1/0	DESCRIPTION					
EN	3	I	Enable input (VBAT enabled, GND disabled)					
FB	4	I	age feedback for programming the output voltage					
GND	2		IC ground connection for logic and power					
SW	1	- 1	Boost and rectifying switch input					
VBAT	6	I	Supply voltage					
VOUT	5	0	Boost converter output					

FUNCTIONAL BLOCK DIAGRAM (ADJUSTABLE VERSION)





PARAMETER MEASUREMENT INFORMATION

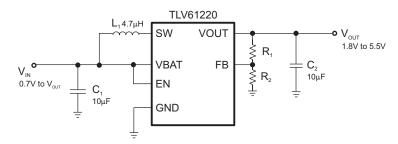


Table 1. List of Components:

COMPONENT REFERENCE	PART NUMBER	MANUFACTURER	VALUE
C ₁	GRM188R60J106ME84D	Murata	10 μF, 6.3V. X5R Ceramic
C ₂	GRM188R60J106ME84D	Murata	10 μF, 6.3V. X5R Ceramic
L ₁	1269AS-H-4ZR7N	Toko	4.7 μH
R ₁ , R ₂			R_1 = 1M Ω , R_2 = Values depending on the programmed output voltage

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NSTRUMENTS

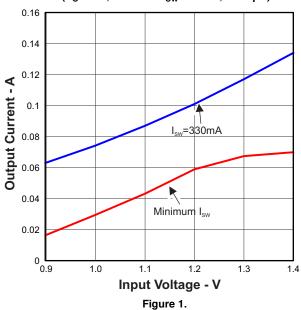
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TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
	Input Voltage, I _{SW} = 330 mA, Minimum I _{SW} = 200 mA, V _O = 1.8V	1
Output Current	Input Voltage, I_{SW} = 400 mA, Minimum I_{SW} = 200 mA, V_O = 3.3V	2
	Input Voltage, I_{SW} = 380 mA, Minimum I_{SW} = 200 mA, V_O = 5V	3
	vs Output Current, V _O = 1.8 V, V _I = [0.7 V; 1.2 V; 1.5 V]	4
Efficiency	vs Output Current, V _O = 3.3 V, V _I = [0.7 V; 1.2 V; 2.4V; 3V]	5
	vs Output Current, V _O = 5 V, V _I = [0.7 V; 1.2 V; 3.6V; 4.2V]	6
	vs Input Voltage, $V_0 = 1.8 \text{ V}$, $I_0 = [100 \mu\text{A}; 1\text{mA}; 10\text{mA}; 50\text{mA}]$	7
Efficiency	vs Input Voltage, $V_0 = 3.3 \text{ V}$, $I_0 = [100 \mu\text{A}; 1\text{mA}; 10\text{mA}; 50\text{mA}]$	8
	vs Input Voltage, $V_0 = 5 \text{ V}$, $I_0 = [100\mu\text{A}; 1\text{mA}; 10\text{mA}; 50\text{mA}]$	9
Outrout Maltage	vs Output Current, , V _O = 1.8 V, V _I = [0.7 V; 1.2 V]	10
Output Voltage	vs Output Current, , $V_0 = 3.3 \text{ V}$, $V_1 = [0.7 \text{ V}; 1.2 \text{ V}; 2.4 \text{ V}]$	11
	Load transient, $V_I = 1.2 \text{ V}$, $V_O = 3.3 \text{ V}$, $I_O = 5\text{mA}$ to 20 mA	12
Waveforms	Line transient, $V_I = 1.8 \text{ V}$ to 2.4V, $V_O = 3.3 \text{ V}$, $I_O = 30 \text{ mA}$	13
	Startup after Enable, V_I = 1.2 V, V_O = 3.3 V, R_{LOAD} = 50 Ω	14

$\begin{array}{l} \text{MAXIMUM OUTPUT CURRENT vs INPUT VOLTAGE} \\ \text{(V}_{0}\text{=}1.8\text{V}, \, \text{Minimum I}_{\text{SW}}\text{=}200\text{mA}, \, \text{L}\text{=}4.7\mu\text{H}) \end{array}$



MAXIMUM OUTPUT CURRENT vs INPUT VOLTAGE (V_O=3.3V, Minimum I_{SW}=200mA, L=4.7µH)

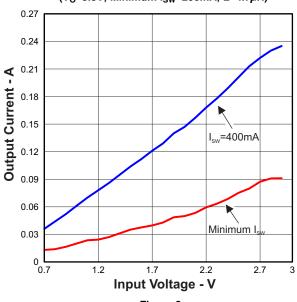
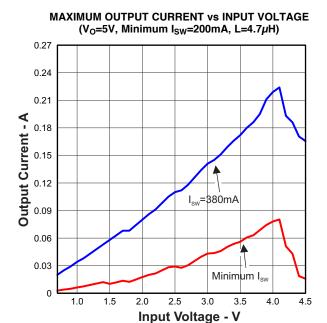
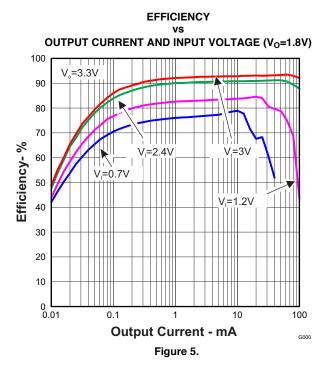


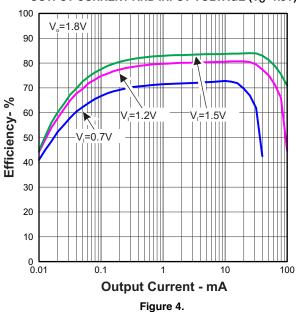
Figure 2.

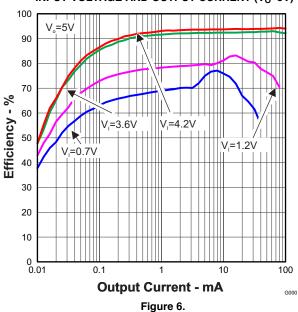






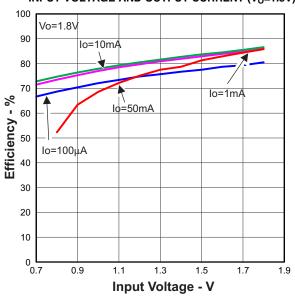












EFFICIENCY vs INPUT VOLTAGE AND OUTPUT CURRENT (V_O=5V)

Figure 7.

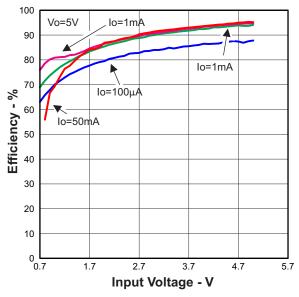
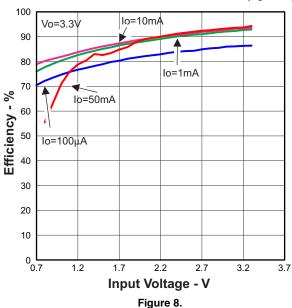
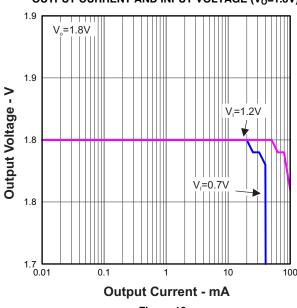


Figure 9.



OUTPUT VOLTAGE vs $\label{eq:control} \text{OUTPUT CURRENT AND INPUT VOLTAGE (V_0=1.8V)}$





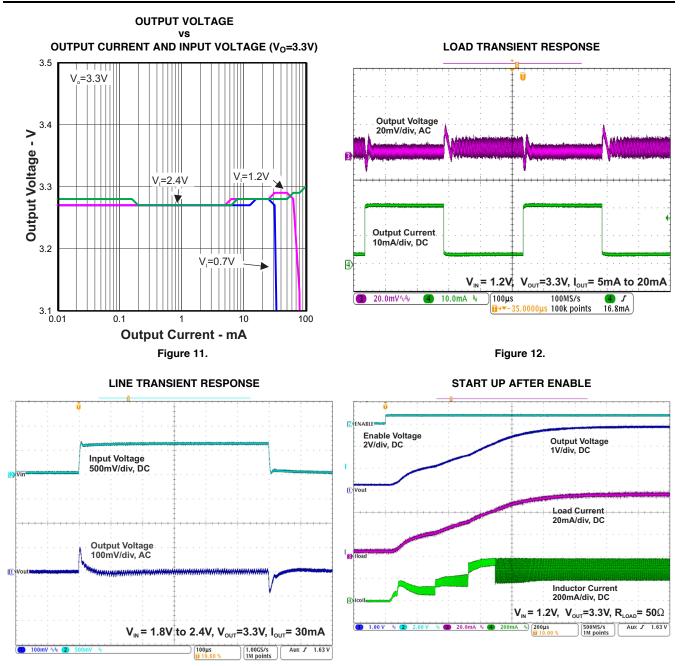


Figure 13. Figure 14.



DETAILED DESCRIPTION

OPERATION

The TLV61220 is a high performance, high efficient boost converter. To achieve high efficiency the power stage is realized as a synchronous boost topology. For the power switching two actively controlled low $R_{DS(on)}$ power MOSFETs are implemented.

CONTROLLER CIRCUIT

The device is controlled by a hysteretic current mode controller. This controller regulates the output voltage by keeping the inductor ripple current constant in the range of 200 mA and adjusting the offset of this inductor current depending on the output load. In case the required average input current is lower than the average inductor current defined by this constant ripple the inductor current gets discontinuous to keep the efficiency high at low load conditions.

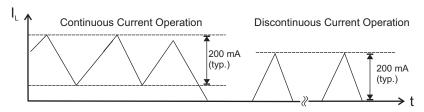


Figure 15. Hysteretic Current Operation

The output voltage V_{OUT} is monitored via the feedback network which is connected to the voltage error amplifier. To regulate the output voltage, the voltage error amplifier compares this feedback voltage to the internal voltage reference and adjusts the required offset of the inductor current accordingly. At fixed output voltage versions an internal feedback network is used to program the output voltage, at adjustable versions an external resistor divider needs to be connected.

The self oscillating hysteretic current mode architecture is inherently stable and allows fast response to load variations. It also allows using inductors and capacitors over a wide value range.

Device Enable and Shutdown Mode

The device is enabled when EN is set high and shut down when EN is low. During shutdown, the converter stops switching and all internal control circuitry is turned off. In this case the input voltage is connected to the output through the back-gate diode of the rectifying MOSFET. This means that there always will be voltage at the output which can be as high as the input voltage or lower depending on the load.

Startup

After the EN pin is tied high, the device starts to operate. In case the input voltage is not high enough to supply the control circuit properly a startup oscillator starts to operate the switches. During this phase the switching frequency is controlled by the oscillator and the maximum switch current is limited. As soon as the device has built up the output voltage to about 1.8 V, high enough for supplying the control circuit, the device switches to its normal hysteretic current mode operation. The startup time depends on input voltage and load current.

Operation at Output Overload

If in normal boost operation the inductor current reaches the internal switch current limit threshold the main switch is turned off to stop further increase of the input current.

In this case the output voltage will decrease since the device can not provide sufficient power to maintain the set output voltage.

If the output voltage drops below the input voltage the backgate diode of the rectifying switch gets forward biased and current starts flow through it. This diode cannot be turned off, so the current finally is only limited by the remaining DC resistances. As soon as the overload condition is removed, the converter resumes providing the set output voltage.

10



Undervoltage Lockout

An implemented undervoltage lockout function stops the operation of the converter if the input voltage drops below the typical undervoltage lockout threshold. This function is implemented in order to prevent malfunctioning of the converter.

Overvoltage Protection

If, for any reason, the output voltage is not fed back properly to the input of the voltage amplifier, control of the output voltage will not work anymore. Therefore an overvoltage protection is implemented to avoid the output voltage exceeding critical values for the device and possibly for the system it is supplying. For this protection the TLV61220 output voltage is also monitored internally. In case it reaches the internally programmed threshold of 6.5 V typically the voltage amplifier regulates the output voltage to this value.

If the TLV61220 is used to drive LEDs, this feature protects the circuit if the LED fails.

Overtemperature Protection

The device has a built-in temperature sensor which monitors the internal IC junction temperature. If the temperature exceeds the programmed threshold (see electrical characteristics table), the device stops operating. As soon as the IC temperature has decreased below the programmed threshold, it starts operating again. To prevent unstable operation close to the region of overtemperature threshold, a built-in hysteresis is implemented.

Product Folder Link(s): TLV61220

APPLICATION INFORMATION

DESIGN PROCEDURE

The TLV61220 is intended for systems powered by a single cell battery to up to three Alkaline, NiCd or NiMH cells with a typical terminal voltage between 0.7 V and 5.5 V. They can also be used in systems powered by one-cell Li-lon or Li-Polymer batteries with a typical voltage between 2.5 V and 4.2 V. Additionally, any other voltage source with a typical output voltage between 0.7 V and 5.5 V can be used with the TLV61220.

Adjustable output voltage version

An external resistor divider is used to adjust the output voltage. The resistor divider needs to be connected between VOUT, FB and GND as shown in Figure 16. When the output voltage is regulated properly, the typical voltage value at the FB pin is 500 mV for the adjustable devices. The maximum recommended value for the output voltage is 5.5 V. The current through the resistive divider should be about 100 times greater than the current into the FB pin. The typical current into the FB pin is 0.01 μ A, and the voltage across the resistor between FB and GND, R₂, is typically 500 mV. Based on those two values, the recommended value for R₂ should be lower than 500 k Ω , in order to set the divider current to 1 μ A or higher. The value of the resistor connected between VOUT and FB, R₁, depending on the needed output voltage (V_{OUT}), can be calculated using Equation 1:

$$R_1 = R_2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1 \right) \tag{1}$$

As an example, if an output voltage of 3.3 V is needed, a 1-M Ω resistor is calculated for R₁ when for R₂ a 180-k Ω has been selected.

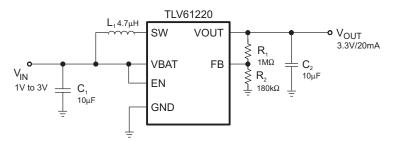


Figure 16. Typical Application Circuit for Adjustable Output Voltage Option

Inductor Selection

To make sure that the TLV61220 can operate, a suitable inductor must be connected between pin VBAT and pin SW. Inductor values of 4.7 µH show good performance over the whole input and output voltage range.

Choosing other inductance values affects the switching frequency f proportional to 1/L as shown in Equation 2.

$$L = \frac{1}{f \times 200 \text{ mA}} \times \frac{V_{IN} \times (V_{OUT} - V_{IN})}{V_{OUT}}$$
(2)

Choosing inductor values higher than 4.7 μ H can improve efficiency due to reduced switching frequency and; therefore, with reduced switching losses. Using inductor values below 2.2 μ H is not recommended.

Having selected an inductance value, the peak current for the inductor in steady state operation can be calculated. Equation 3 gives the peak current estimate.

$$I_{L,MAX} = \begin{cases} \frac{V_{OUT} \times I_{OUT}}{0.8 \times V_{IN}} + 100 \text{ mA}; & \text{continous current operation} \\ 200 \text{ mA}; & \text{discontinuous current operation} \end{cases}$$
(3)

(0



For selecting the inductor this would be the suitable value for the current rating. It also needs to be taken into account that load transients and error conditions may cause higher inductor currents.

Equation 4 helps to estimate whether the device will work in continuous or discontinuous operation depending on the operating points. As long as the inequation is true, continuous operation is typically established. If the inequation becomes false, discontinous operation is typically established.

$$\frac{V_{\text{OUT}} \times I_{\text{OUT}}}{V_{\text{IN}}} > 0.8 \times 100 \text{ mA}$$
(4)

The following inductor series from different suppliers have been used with TLV61220 converters:

VENDOR INDUCTOR SERIES Toko DFE252010C EPL3015 Coilcraft EPL2010 Murata LQH3NP Taiyo Yuden NR3015 Wurth Elektronik WE-TPC Typ S

Table 2. List of Inductors

Capacitor Selection

Input Capacitor

At least a 10-µF input capacitor is recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor placed as close as possible to the VBAT and GND pins of the IC is recommended.

Output Capacitor

For the output capacitor C_2 , it is recommended to use small ceramic capacitors placed as close as possible to the VOUT and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which can not be placed close to the IC, the use of a small ceramic capacitor with an capacitance value of around 2.2µF in parallel to the large one is recommended. This small capacitor should be placed as close as possible to the VOUT and GND pins of the IC.

A minimum capacitance value of 4.7 µF should be used, 10 µF are recommended. If the inductor value exceeds 4.7 µH, the value of the output capacitance value needs to be half the inductance value or higher for stability reasons, see Equation 5.

$$C_2 \ge \frac{L}{2} \times \frac{\mu F}{\mu H} \tag{5}$$

The TLV61220 is not sensitive to the ESR in terms of stability. Using low ESR capacitors, such as ceramic capacitors, is recommended anyway to minimize output voltage ripple. If heavy load changes are expected, the output capacitor value should be increased to avoid output voltage drops during fast load transients.

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Layout Considerations

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground paths. The input and output capacitor, as well as the inductor should be placed as close as possible to the IC.

The feedback divider should be placed as close as possible to the control ground pin of the IC. To lay out the ground, it is recommended to use short traces as well, separated from the power ground traces. This avoids ground shift problems, which can occur due to superimposition of power ground current and control ground current. Assure that the ground traces are connected close to the device GND pin.

THERMAL INFORMATION

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below.

- · Improving the power-dissipation capability of the PCB design
- · Improving the thermal coupling of the component to the PCB
- · Introducing airflow in the system

For more details on how to use the thermal parameters in the dissipation ratings table please check the Thermal Characteristics Application Note (SZZA017) and the IC Package Thermal Metrics Application Note (SPRA953).

Submit Documentation Feedback



PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TLV61220DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VUAI	Samples
TLV61220DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VUAI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV61220DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV61220DBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

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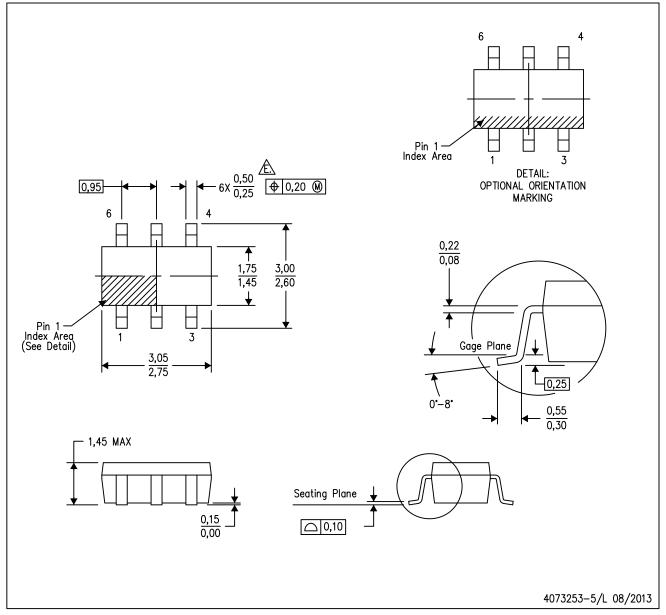


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV61220DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TLV61220DBVT	SOT-23	DBV	6	250	180.0	180.0	18.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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